



MDS100

High-end Power Semiconductor Manufacturer

**Three Phases Rectification Bridge Modules****Features:**

- Isolated mounting base 2500V
- Solder joint technology
- Space and weight savings

$I_o$	<b>100 A</b>
$V_{RRM}$	<b>600~2200 V</b>
$I_{FSM}$	<b>0.60 KA</b>
$I^2t$	<b>1.8 10<sup>3</sup>A<sup>2</sup>s</b>

**Typical Applications**

- DC Power supplies for equipments.
- DC supply for PWM inverter
- Inverter Welder

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j$ (°C)	VALUE			UNIT
				Min	Type	Max	
$I_o$	DC output current	Three-phase full wave rectifying circuit, $T_c=100^\circ C$	150			100	A
$I_{RRM}$	Repetitive peak current	at $V_{RRM}$	150			8	mA
$I_{FSM}$	Surge forward current	10ms half sine wave $V_R=0$	150			0.6	kA
$I^2t$	$I^2t$ for fusing coordination					1.8	10 <sup>3</sup> A <sup>2</sup> s
$V_{FO}$	Threshold voltage		150			0.7	V
$r_F$	Forward slope resistance					4.5	mW
$V_{FM}$	Peak forward voltage	$I_{FM}=100A$	25			1.30	V
$R_{th(j-c)}$	Thermal resistance Junction to case	Single side cooled, per total				0.20	°C/W
$R_{th(c-h)}$	Thermal resistance case to heatsink	Single side cooled, per total				0.07	°C/W
$V_{iso}$	Isolation voltage	50Hz,R.M.S,t=1min, $I_{iso}:1mA$ (max)		2500			V
$F_m$	Terminal connection torque(M5)			2.5		4.0	N·m
	Mounting torque(M5)			2.5		4.0	N·m
$T_{vj}$	Junction temperature			-40		150	°C
$T_{stg}$	Stored temperature			-40		125	°C
$W_t$	Weight				135		g
Outline	T13						

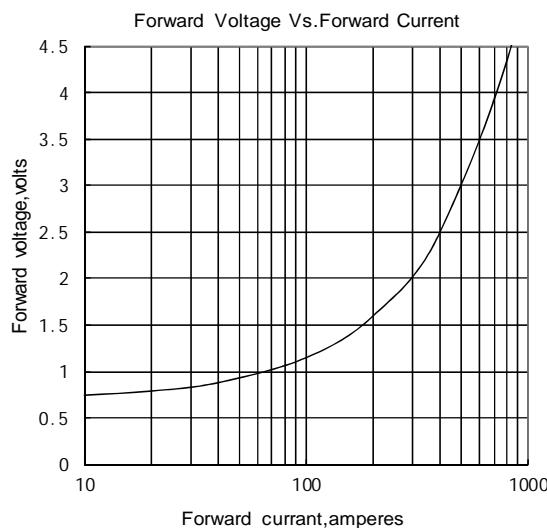


Fig.1

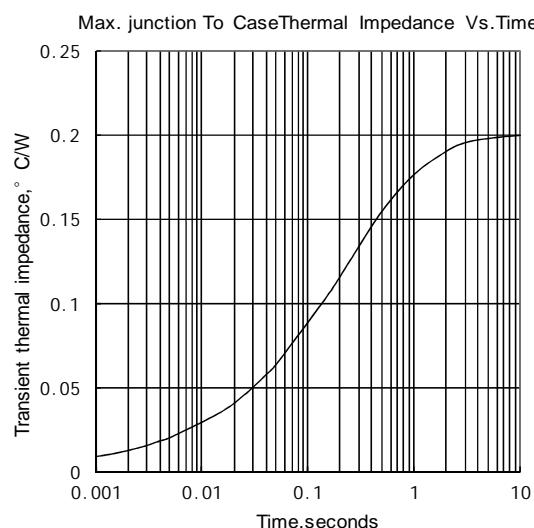


Fig.2

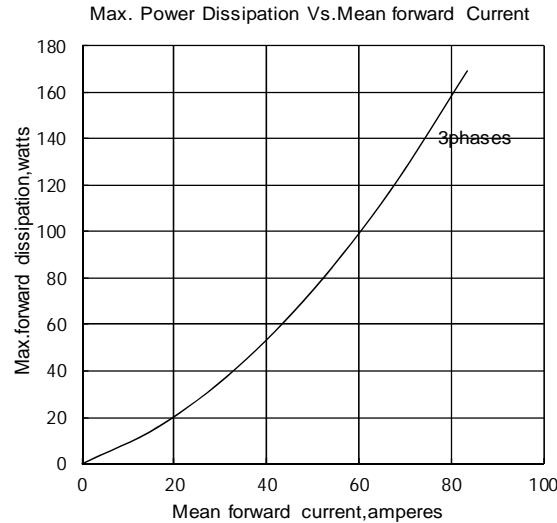


Fig.3

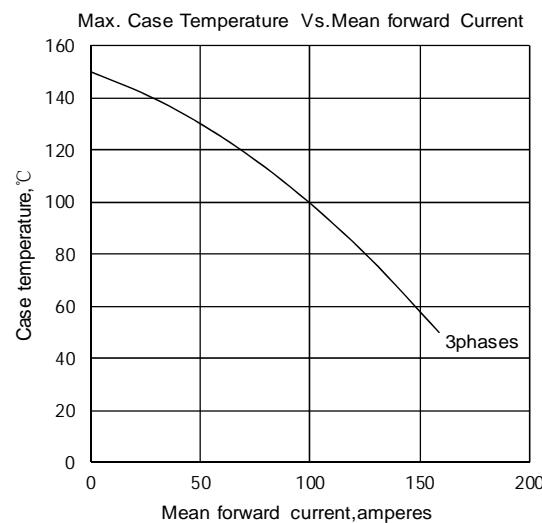


Fig.4

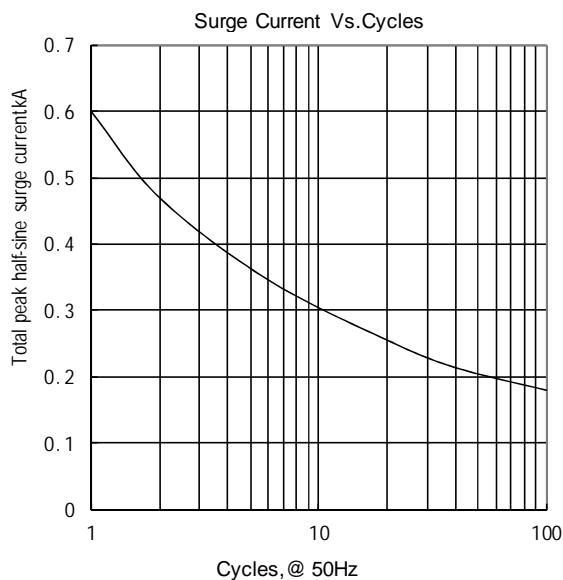


Fig.5

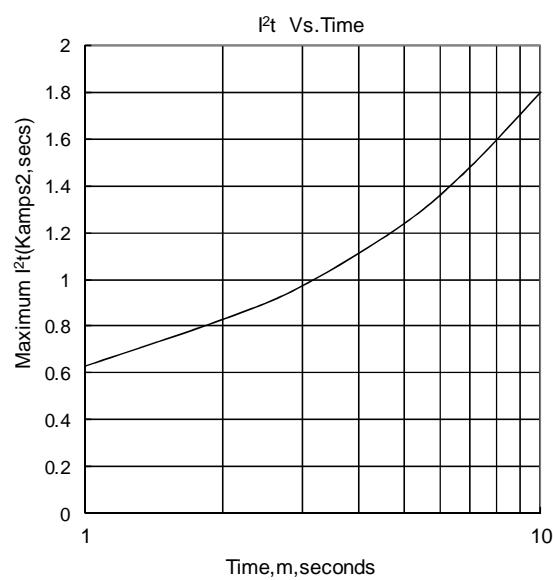
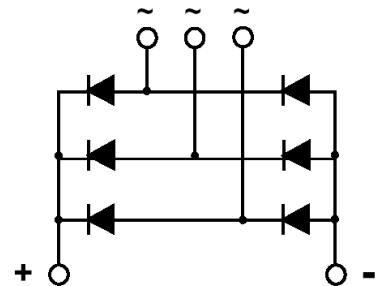
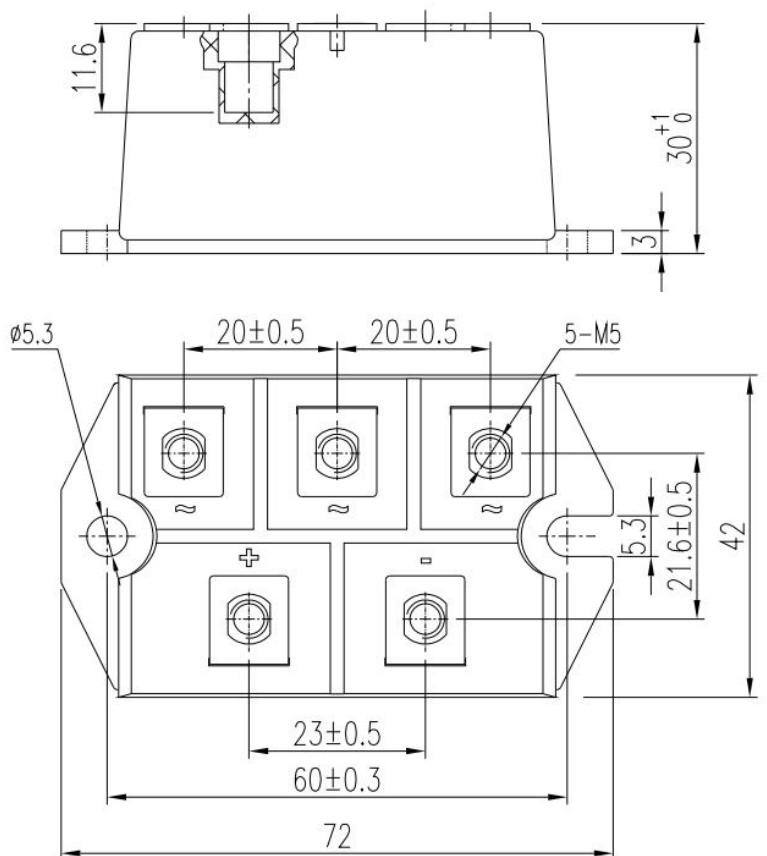


Fig.6

**Outline:**

Unmarked dimensional tolerance: ±0.5mm

T13